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BIB DATA SHEET

CONFIRMATION NO. 5852

** FOREIGN APPLICATIONS *** JAPAN P2002-338452 11/21/2002												
RULE APPLICANTS Tadashi Iguchi, Mie-ken, JAPAN; Katsuhiro Ishida, Mie-ken, JAPAN; Hirohaki Tsunoda, Mie-ken, JAPAN; Hirohaki Izuka, Mie-ken, JAPAN; Hirohaki	SERIAL NUMBER		DATE `´					NO.				
APPLICANTS Tadashi Iguchi, Mie-ken, JAPAN; Katsuhiro Ishida, Mie-ken, JAPAN; Hironaki Tsunoda, Mie-ken, JAPAN; Hironaki Isuuda, Mie-ken, JAPAN; Hironaki Isuuda, Mie-ken, JAPAN; Hironaki Isuuda, Mie-ken, JAPAN; Hironaki Isuuda, Mie-ken, JAPAN; Seilichi Mori, Tokyo, JAPAN; Seili	10/612,03			003	257		2826		03180.0326			
Tadashi Iguchi, Mie-ken, JAPAN; Katsuhiro Ishida, Mie-ken, JAPAN; Hirohisa Iizuka, Mie-ken, JAPAN; Seiichi Mori, Tokyo, JA			RULI	E								
FOREIGN APPLICATIONS JAPAN P2002-338452 11/21/2002 FIF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 09/26/2003 Foreign Priority claimed	Tadashi (guchi, Mie-ken, JAPAN; Katsuhiro Ishida, Mie-ken, JAPAN; Hiroaki Tsunoda, Mie-ken, JAPAN; Hirohisa lizuka, Mie-ken, JAPAN; Hiroaki Hazama, Tokyo, JAPAN;											
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ADDRESS FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER LLP 901 NEW YORK AVENUE, NW WASHINGTON, DC 20001-4413 UNITED STATES TITLE SEMICONDUCTOR MEMORY PREVENTING AN ELECTRIC SHORT CIRCUIT BETWEEN A WORD LINE AND A SEMICONDUCTOR SUBSTRATE, AND MANUFACTURING METHOD FOR THE SEMICONDUCTOR MEMORY FILING FEE RECEIVED 1224 RECEIVED 1224 RECEIVED 11.18 Fees (Issue) 11.18 Fees (Issue) 11.18 Fees (Issue) 11.18 Fees (Issue)	** IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 09/26/2003											
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